

2815



SEP 03 2002

TRANSMITTAL LETTER
(General - Patent Pending)

Docket No.
90065.001020/17732.8011.00

In Re Application Of: Martin E. Kordes, et al.

Serial No.
09/682,151

Filing Date
July 27, 2001

Examiner
Chris C. Chu

Group Art Unit
2815

Title: CONTACT METHOD FOR THIN SILICON CARBIDE EPITAXIAL LAYER AND SEMICONDUCTOR DEVICES FORMED BY THOSE METHODS

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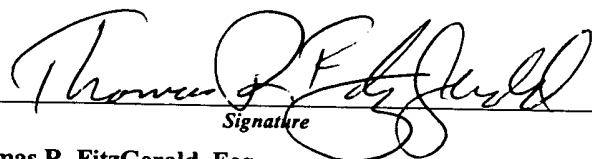
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in the above identified application.

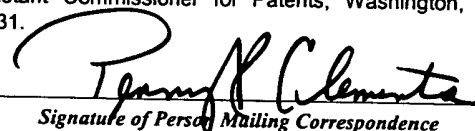
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Dated: 8/2/02

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CERTIFICATE OF MAILING BY FIRST CLASS MAIL (37 CFR 1.8)Applicant(s): **Martin E. K. Friesch, et al.**

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Invention: **CONTACT METHOD FOR THIN SILICON CARBIDE EPITAXIAL LAYER AND SEMICONDUCTOR DEVICES FORMED BY THOSE METHODS**

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Docket No.
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IN THE UNITED STATES PATENT & TRADEMARK OFFICE

Applicant : Martin E. Kordes, et al.
Serial No. : 09/682,151
Filed : 27 July 2001
For : CONTACT METHOD FOR THIN SILICON
CARBIDE EPITAXIAL LAYER AND
SEMICONDUCTOR DEVICES FORMED BY THOSE
METHODS

) Examiner
) Chris C. Chu
)
) Art Unit:
) 2815
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ASSISTANT COMMISSIONER FOR PATENTS
WASHINGTON, D.C. 20231

Dear Sir:

Applicants elected to file a PCT application and hereby revoke all certifications to the contrary (if any) and consent to publication of the subject application.

Respectfully submitted,

Dated: 8/21/02

Thomas R. FitzGerald
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